Dual N-channel MOSFET

KFCAB21830L
Datasheet

For additional information or question, please contact Nuvoton Technology Corporation Japan.

www.nuvoton.co.jp

1. GENERAL DESCRIPTION

Gate resistor installed Dual N-channel MOSFET
for lithium-ion secondary battery protection circuits.

2. FEATURES

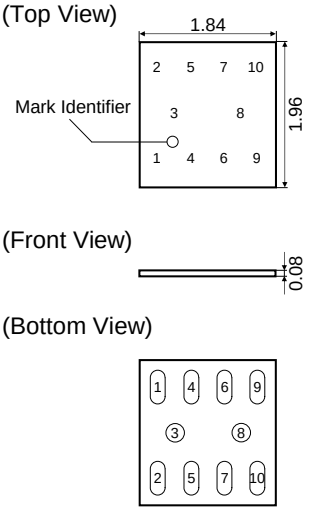
- Source-source On-state Resistance: RSS(on) typ = 2.5 mΩ (VGS = 3.8 V)
- CSP (Chip Size Package)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1)

3. MARKING SYMBOL: W6

4. PACKAGING

Embossed type (Thermo-compression sealing): 10,000 pcs / reel (standard)

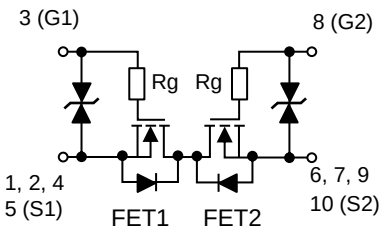
Unit: mm



1, 2, 4, 5. Source1 (FET1) 3. Gate1 (FET1)
6, 7, 9, 10. Source2 (FET2) 8. Gate2 (FET2)

Package	TCSP1820008-N3
JEITA	-
Code	-

Equivalent Circuit



5. ABSOLUTE MAXIMUM RATINGS Ta = 25 °C

Parameter		Symbol	Rating	Unit
Source-source Voltage		VSS	12	V
Gate-source Voltage		VGS	± 8	V
Source Current	DC *1	IS1	12.4	A
	DC *2	IS2	22.0	
	DC *3	IS3	31.0	
	Pulsed *4	ISp	124	
Total Power Dissipation	DC *1	PD1	0.51	W
	DC *2	PD2	1.70	
	DC *3	PD3	3.20	
Operating Junction and Storage Temperature Range		Tj,Tstg	- 55 to + 150	°C

6. THERMAL CHARACTERISTICS Ta = 25 °C

Parameter	Symbol	Rating	Unit
Thermal Resistance (ch-a)	Rth1 *1	245	°C / W
	Rth2 *2	74	
	Rth3 *3	39	

Note *1 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm).
FR4 board partially covered with copper pad (22 mm^2 area, 36 µm thickness).
*2 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm).
FR4 board fully covered with copper pad (604 mm^2 area, 36 µm thickness).
*3 Mounted on ceramic board (70 mm x 70 mm x t1.0 mm).
*4 t = 10 µs, Duty Cycle ≤ 1 %.

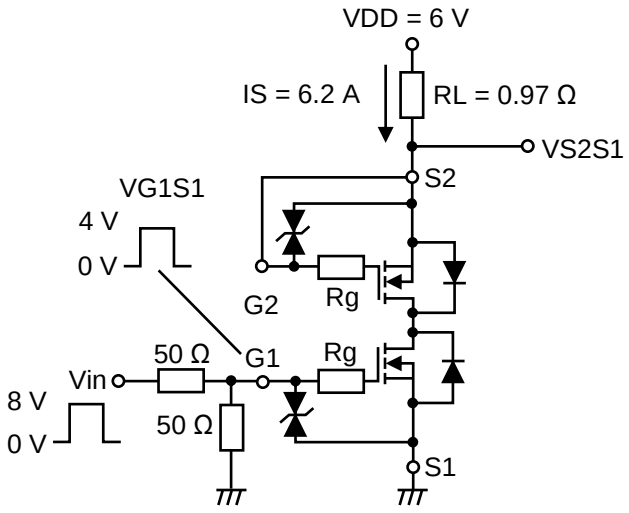
7. ELECTRICAL CHARACTERISTICS Ta = 25 °C ± 3 °C

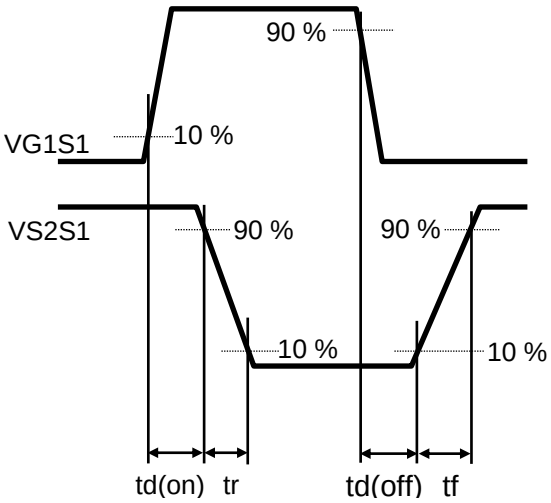
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Source-source Breakdown Voltage	VSSS	IS = 1 mA, VGS = 0 V	12			V
Zero Gate Voltage Source Current	ISSS	VSS = 12 V, VGS = 0 V			1	μA
Gate-source Leakage Current	IGSS1	VGS = ± 8 V, VSS = 0 V			± 10	μA
	IGSS2	VGS = ± 5 V, VSS = 0 V			± 1	
Gate-source Threshold Voltage	Vth	IS = 0.56 mA, VSS = 6 V	0.35	0.90	1.40	V
Source-source On-state Resistance	RSS(on)1	IS = 6.2 A, VGS = 4.5 V	1.6	2.2	2.9	mΩ
	RSS(on)2	IS = 6.2 A, VGS = 3.8 V	1.8	2.5	3.3	
	RSS(on)3	IS = 6.2 A, VGS = 3.1 V	2.1	3.1	5.0	
	RSS(on)4	IS = 6.2 A, VGS = 2.5 V	2.6	4.3	8.5	
Body Diode Forward Voltage	VF(s-s)	IF = 6.2 A, VGS = 0 V		0.7	1.0	V
Input Capacitance *1	Ciss	VSS = 10 V, VGS = 0 V, f = 1 kHz		2230		pF
Output Capacitance *1	Coss			410		
Reverse Transfer Capacitance *1	Crss			330		
Turn-on Delay Time *1,*2	td(on)	VDD = 6 V, VGS = 0 to 4 V		0.8		μs
Rise Time *1,*2	tr	IS = 6.2 A		1.6		
Turn-off Delay Time *1,*2	td(off)	VDD = 6 V, VGS = 4 to 0 V		3.3		μs
Fall Time *1,*2	tf	IS = 6.2 A		2.7		
Total Gate Charge *1	Qg	VDD = 6 V		17		nC
Gate-source Charge *1	Qgs	VGS = 0 to 4 V		7		
Gate-drain Charge *1	Qgd	IS = 12.4 A		4		
Gate Resistance *1	Rg	f = 1 MHz	400	700	1000	Ω

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

*1 Guaranteed by design, not subject to production testing.

*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time.

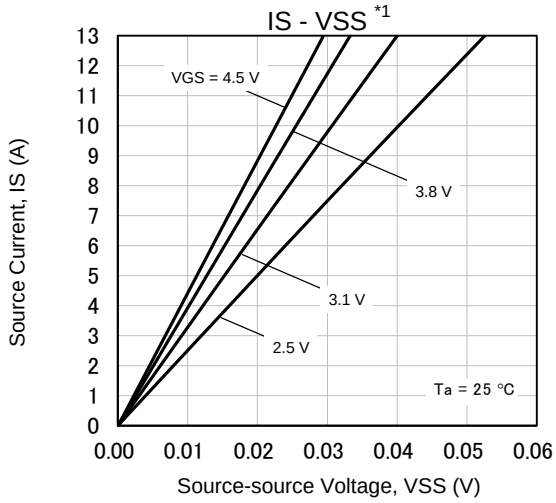


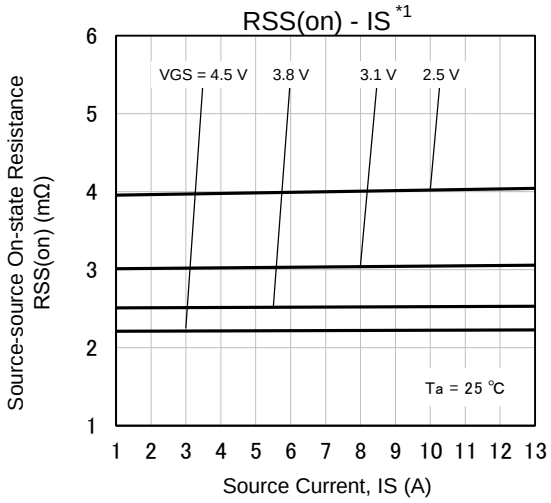


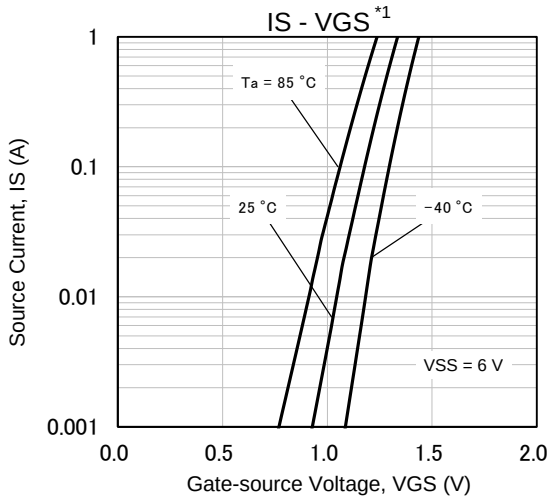
8. ELECTROSTATIC DISCHARGE CHARACTERISTIC Ta = 25 °C ± 3 °C

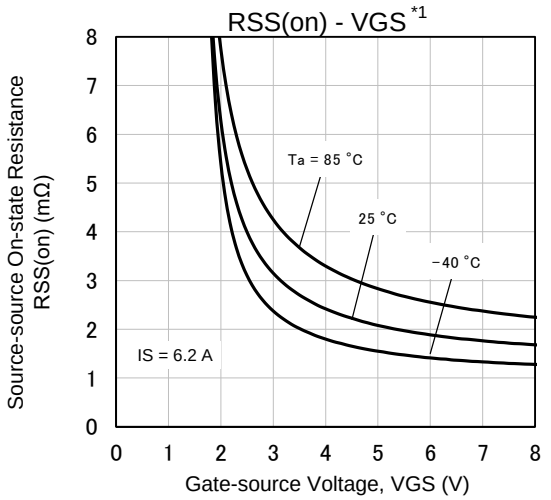
Standard	Test Type	Symbol	Conditions	Class	Value	Unit
AEC-Q101-001	Human Body Model	HBM	C = 100 pF, R = 1.5 kΩ	H2	> 2 to ≤ 4	kV

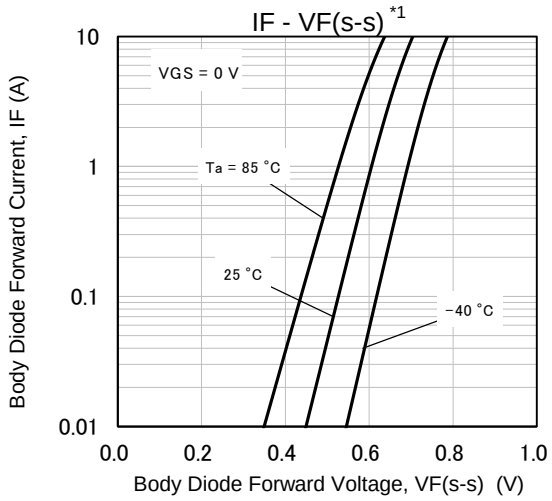
9. TECHNICAL DATA (Reference)

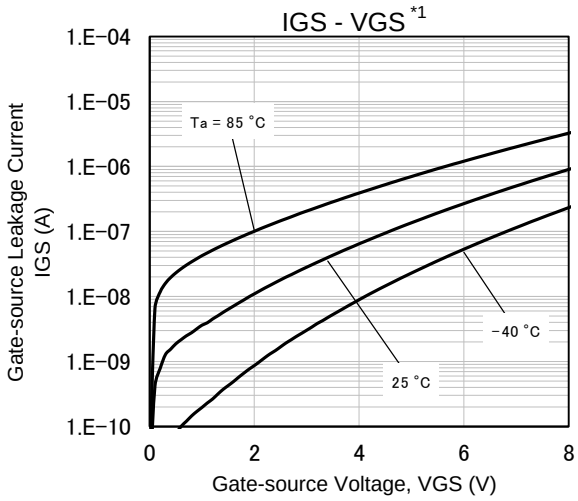






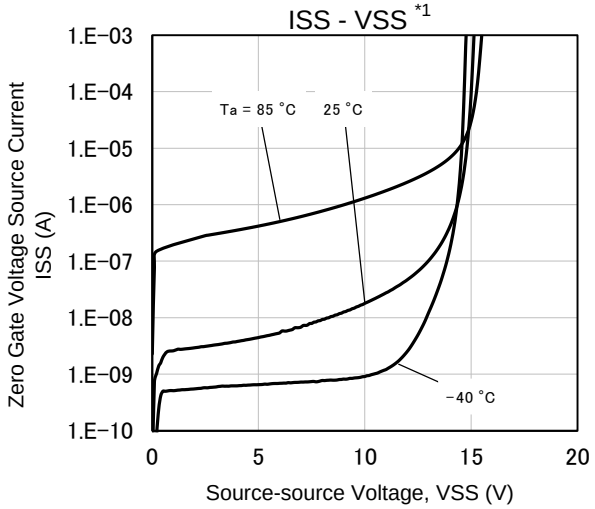




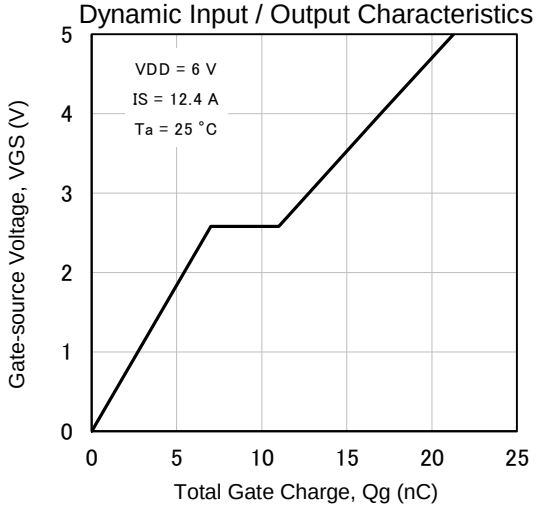


TECHNICAL DATA (Reference)

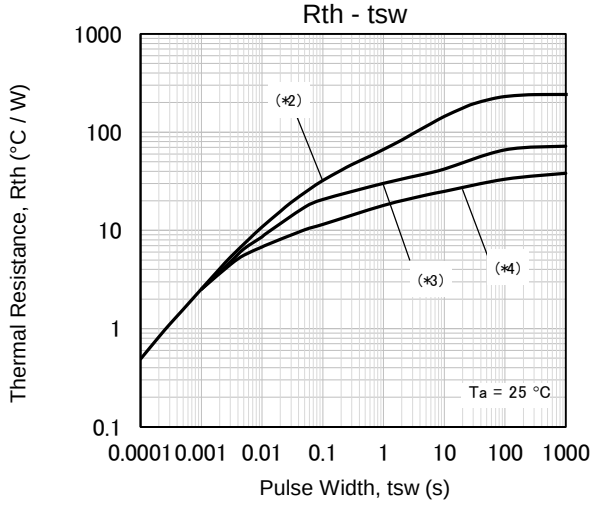
ISS - VSS *1



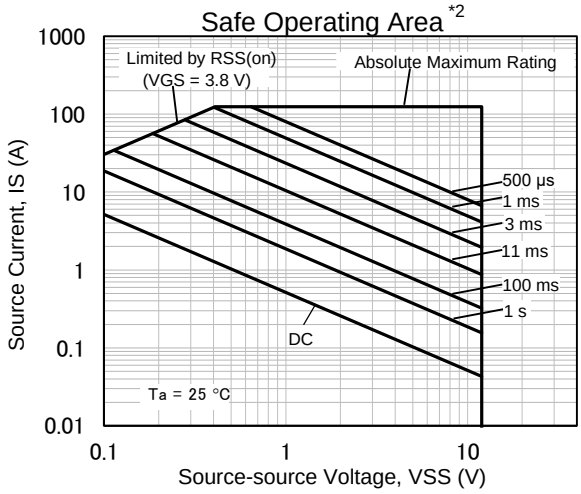
Dynamic Input / Output Characteristics



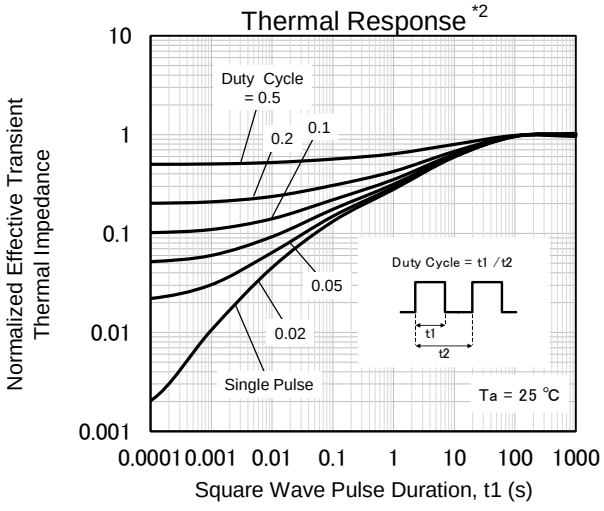
Rth - tsw



Safe Operating Area *2



Thermal Response *2



Note

*1 Pulse measurement.

*2 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm).
FR4 board partially covered with copper pad
(22 mm^2 area, 36 µm thickness).

*3 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm)..
FR4 board fully covered with copper pad
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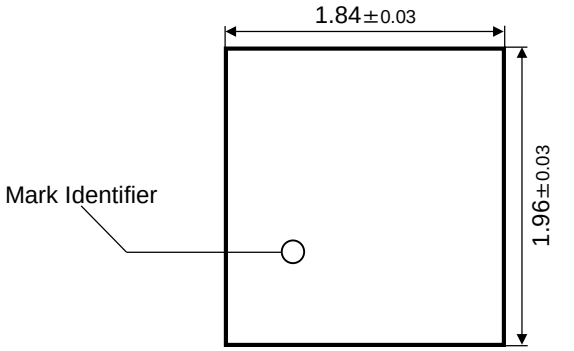
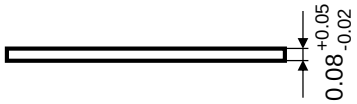
*4 Mounted on ceramic board (70 mm x 70 mm x t1.0 mm).

10. OUTLINE

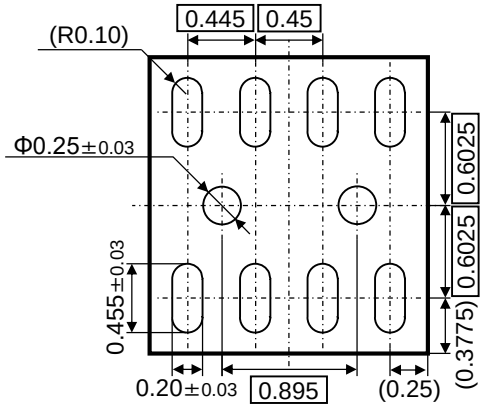
(Top View) Unit: mm



(Front View)

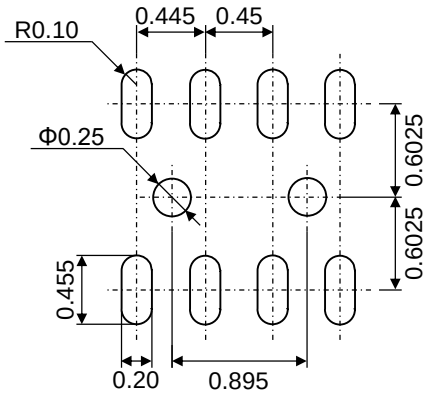


(Bottom View)



11. LAND & STENCIL PATTERN (Reference)

Unit: mm



Important notice:

Solder Mask Defined (SMD) pattern is strongly recommended for pad design.
Please check the information in the Nuvoton WL-CSP Application Notes about mounting process.

12. REVISION HISTORY

Date	Revision	Description
2021.08.31	1.00	1. Initially issued.

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